

**SPECIFICATION AMENDMENTS**

Please replace Table 1 on page 53 with Table 1 as shown below. Also shown below is a clean copy of Table 1 for purposes of scanning.

Table 1

| Substrate No. | Surface configuration parameters of substrate |         |             |          |       | Remarks                                    |
|---------------|---|---------|-------------|----------|-------|--|
|               | Ra (μm)                                       | Mr2 (%) | 100-Mr2 (%) | Rvk (μm) | A2    |  |
| 1             | 0.55  | 88.8    | 11.2        | 0.98     | 5.49  | Invention                                  |
| 2             | 0.48  | 88.6    | 11.4        | 0.77     | 4.39  | Invention                                  |
| 3             | 0.42  | 89.3    | 10.7        | 0.66     | 3.53  | Invention                                  |
| 4             | 0.63  | 88.3    | 11.7        | 1.35     | 7.90  | Invention                                  |
| 5             | 0.81  | 86.9    | 13.1        | 1.74     | 11.40 | <del>Invention</del><br><u>Comparative</u> |
| 6             | 0.66  | 78.8    | 21.2        | 1.56     | 16.54 | Comparative                                |

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